



PI74ALVC162835F

18-Bit Universal Bus Driver with 3-State Outputs

Product Features

- PI74ALVC162835F is designed for low voltage operation, $V_{CC} = 2.3V$ to $3.6V$
- Outputs have equivalent 26Ω series resistors
- Supports PC133 Registered DIMM
- Typical V_{OLP} (Output Ground Bounce) $< 0.8V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Typical V_{OHV} (Output Voh Undershoot) $< 2.0V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Industrial operation at $-40^\circ C$ to $+85^\circ C$
- Packages available:
 - 56-pin 240 mil wide plastic TSSOP (A)
 - 56-pin 173 mil wide plastic TVSOP (K6)
 - 56-pin 300 mil wide plastic SSOP (V)

Product Description

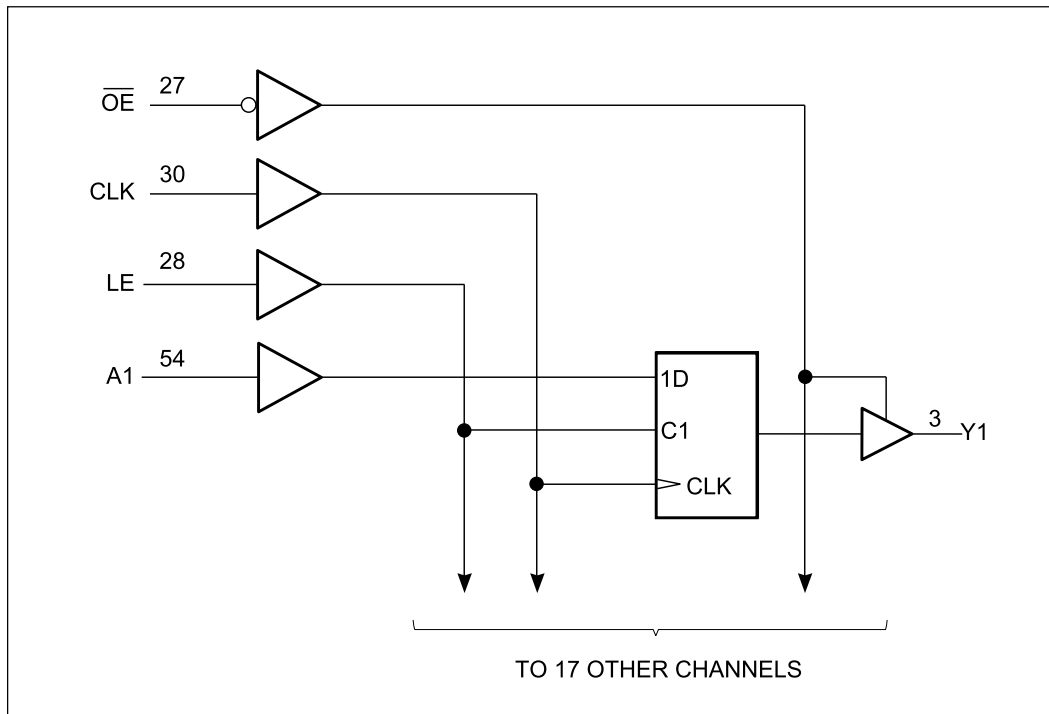
Pericom Semiconductor's PI74ALVC series of logic circuits are produced using the Company's advanced 0.5 micron CMOS technology, achieving industry leading speed.

The 18-bit PI74ALVC162835F universal bus driver is designed for 2.3V to 3.6V V_{CC} operation.

Data flow from A to Y is controlled by Output Enable ($\overline{OE}$). The device operates in the transparent mode when LE is HIGH. The A data is latched if CLK is held at a high or low logic level. If LE is LOW, the A-bus is stored in the latch/flip-flop on the low-to-high transition of CLK. When $\overline{OE}$ is HIGH, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Logic Block Diagram



Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable
CLK	Clock Input
A	Data Input
Y	Data Output
GND	Ground
V _{CC}	Power

Truth Table^{(1)†}

Inputs				Outputs Y
$\overline{OE}$	LE	CLK	A	
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	↑	L	L
L	L	↑	H	H
L	L	H	X	Y ₀ ⁽²⁾
L	L	L	X	Y ₀ ⁽³⁾

Product Pin Configuration

NC	1	56	GND
NC	2	55	NC
Y1	3	54	A1
GND	4	53	GND
Y2	5	52	A2
Y3	6	51	A3
V _{CC}	7	50	V _{CC}
Y4	8	49	A4
Y5	9	48	A5
Y6	10	47	A6
GND	11	46	GND
Y7	12	45	A7
Y8	13	44	A8
Y9	14	43	A9
Y10	15	42	A10
Y11	16	41	A11
Y12	17	40	A12
GND	18	39	GND
Y13	19	38	A13
Y14	20	37	A14
Y15	21	36	A15
V _{CC}	22	35	V _{CC}
Y16	23	34	A16
Y17	24	33	A17
GND	25	32	GND
Y18	26	31	A18
$\overline{OE}$	27	30	CLK
LE	28	29	GND

Notes:

- H = High Signal Level
L = Low Signal Level
Z = High Impedance
↑ = Transition LOW-to-HIGH
X = Irrelevant
- Output level before the indicated steady-state input conditions were established, provided that CLK is high before LE goes low.
- Output level before the indicated steady-state input conditions were established.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65°C to +150°C
Ambient Temperature with Power Applied	-40°C to +85°C
Input Voltage Range, V_{IN}	-0.5V to $V_{CC} + 0.5V$
Output Voltage Range, V_{OUT}	-0.5V to $V_{CC} + 0.5V$
DC Input Voltage	-0.5V to +5.0V
DC Output Current	100mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽¹⁾

Parameters	Description	Test Conditions	Min.	Typ.	Max.	Units
V_{CC}	Supply Voltage		2.3		3.6	V
V_{IH}	Input HIGH Voltage	$V_{CC} = 2.3V$ to $2.7V$	1.7			
		$V_{CC} = 2.7V$ to $3.6V$	2.0			
V_{IL}	Input LOW Voltage	$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 2.7V$ to $3.6V$			0.8	
V_{IN}	Input Voltage		0		V_{CC}	
V_{OUT}	Output Voltage		0		V_{CC}	
I_{OH}	High-level Output Current	$V_{CC} = 2.3V$			-6	mA
		$V_{CC} = 2.7V$			-8	
		$V_{CC} = 3.0V$			-12	
I_{OL}	Low-level Output Current	$V_{CC} = 2.3V$			6	
		$V_{CC} = 2.7V$			8	
		$V_{CC} = 3.0V$			12	
T_A	Operating Free-Air Temperature		-40		85	°C

Note:

- Unused control inputs must be held HIGH or LOW to prevent them from floating.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 3.3\text{V} \pm 10\%$)

Parameter	Conditions		$V_{CC}^{(1)}$	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units
V_{OH}	$I_{OH} = -100\mu\text{A}$		Min.. to Max.	$V_{CC} - 0.2$			V
	$I_{OH} = -4\text{mA}$	$V_{IH} = 1.7\text{V}$	2.3V	1.9			
	$I_{OH} = -6\text{mA}$	$V_{IH} = 1.7\text{V}$	2.3V	1.7			
		$V_{IH} = 2.0\text{V}$	3.0V	2.4			
	$I_{OH} = -8\text{mA}$	$V_{IH} = 2.0\text{V}$	2.7V	2.0			
	$I_{OH} = -12\text{mA}$	$V_{IH} = 2.0\text{V}$	3.0V	2.0			
V_{OL}	$I_{OH} = 100\mu\text{A}$		Min.. to Max.			0.2	V
	$I_{OH} = 4\text{mA}$	$V_{IL} = 0.7\text{V}$	2.3V			0.4	
	$I_{OH} = 6\text{mA}$	$V_{IL} = 0.7\text{V}$	2.3V			0.55	
		$V_{IL} = 0.8\text{V}$	3.0V			0.55	
	$I_{OH} = 8\text{mA}$	$V_{IL} = 0.8\text{V}$	2.7V			0.6	
	$I_{OH} = 12\text{mA}$	$V_{IL} = 0.8\text{V}$	3.0V			0.8	
I_I	$V_I = V_{CC}$ or GND		3.6V			± 5	μA
I_{OZ}	$V_O = V_{CC}$ or GND		3.6V			± 5	
I_{CC}	$V_I = V_{CC}$ or GND		3.6V			40	
ΔI_{CC}	One input at $V_{CC} - 0.6\text{V}$, Other inputs a V_{CC} or GND		3V to 3.6V			750	
C_I Controls Inputs	$V_I = V_{CC}$ or GND		3.3V		4.0		pF
Data Input	$V_O = V_{CC}$ or GND		3.3V		4.0		
C_O Outputs	$V_O = V_{CC}$ or GND		3.3V		5.0		

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient and maximum loading.
3. For I/O ports, the I_{OZ} includes the input leakage current.

Timing Requirements over Operating Range

Parameters	Description	V _{CC} = 2.5 V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
f _{CLOCK}	Clock frequency	0	150	0	150	0	150	MHz
t _W Pulse Duration	LE high	3.3		3.3		3.3		ns
	CLK high or low	3.3		3.3		3.3		
t _{SU} Setup time	Data before CLK↑	2.2		2.1		1		
	Data before LE↓, CLK High	1.9		1.6		1.5		
	Data before LE↓, CLK Low	1.3		1.1		1		
t _H Hold time	Data after CLK↑	0.6		0.6		0.6		
	Data after LE↓, CLK High or Low	1.4		1.7		1.4		
Δt/Δv ⁽¹⁾	Input Transition Rise or Fall	0	10	0	10	0	10	ns/V

Note:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

Switching Characteristics Over Operating Range⁽¹⁾

Parameters	From (Input)	To (Output)	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
f _{MAX}			150		150		150		MHz
t _{PD}	A	Y	1	5		5	1	4.2	ns
t _{PD}	LE	Y	1.3	5.9		5.8	1.3	5.1	
t _{PD}	CLK	Y	1.4	6.3		6.1	1.4	3.5	
t _{EN}	$\overline{\text{OE}}$	Y	1.4	6.3		6.5	1.1	5.5	
t _{DIS}	$\overline{\text{OE}}$	Y	1	4.9		4.9	1.3	4.5	

Notes:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

Operating Characteristics, T_A = 25°C

Parameters		Test Conditions	V _{CC} = 2.5V ± 0.2V	V _{CC} = 3.3V ± 0.3V	Units
			Typical	Typical	
C _{PD} Power Dissipation Capacitance	Outputs Enabled	C _L = 0pF, F = 10 MHz	35.5	40	pF
	Outputs Disabled		12.5	14	